

Garfield Simulation of CGEM

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Outline

- Introduction
- Method
- Lorentz Angle
- Primary ionization
- Electron shift
- Avalanche & Gain

Introduction

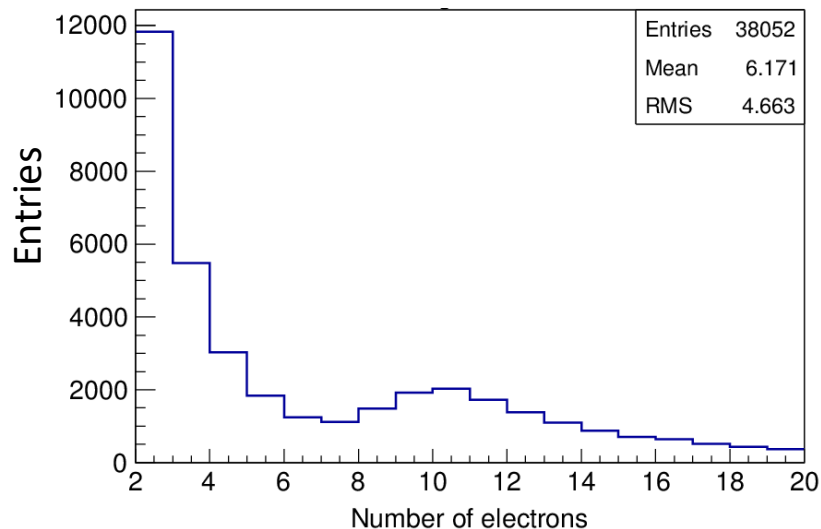
- Garfield is time consuming for the full triple-GEM simulation. So we will simulate the three GEMs separately.
- The incident particle interacts with gas and creates primary electrons.
- For “electron cluster”, it refers to the energy loss in a single ionizing collision of the primary charged particle and the secondary electrons produced in this process.

Method

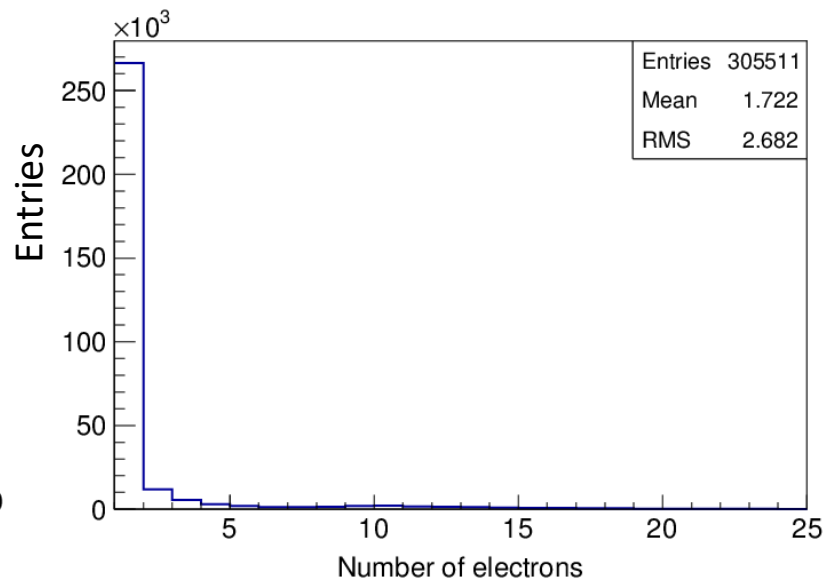
- Software
 - ANSYS: to model & mesh the GEM
 - Garfield++: to simulate electron avalanches
 - ROOT and C scripts: to analyse the data
- Garfield Simulation
 - Gas Mixture: Ar: iC4H10 (90: 10)
 - Avalanche Model: AvalancheMicroscopic
 - Particle: 20k orthogonal μ tracks with momentum 1Gev/c for primary electrons simulation. 20k electrons for electron avalanches simulation.
 - Magnetic Field: 1Tesla
 - High voltages on foils : 270V/GEM
 - Field: 1.5/3/3/5 kV/cm
(Drift/Transfer1/Transfer2/Induction)

Primary ionization

Range 2~20



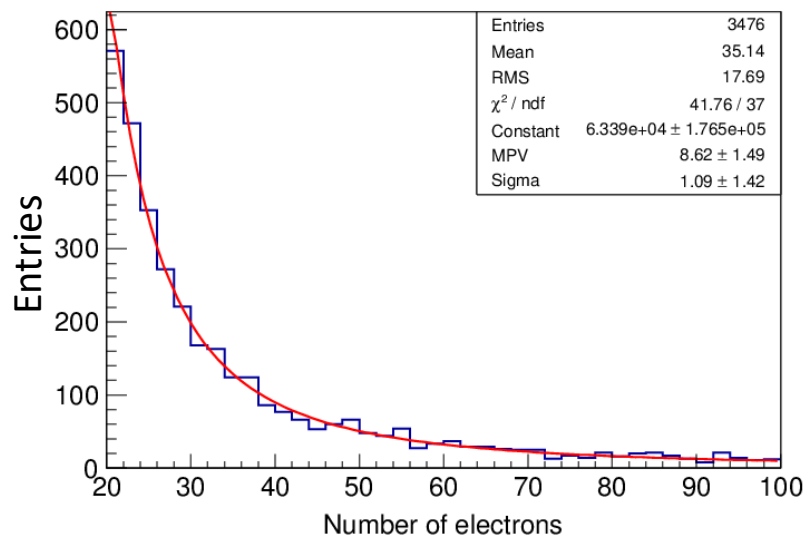
Range 1~25



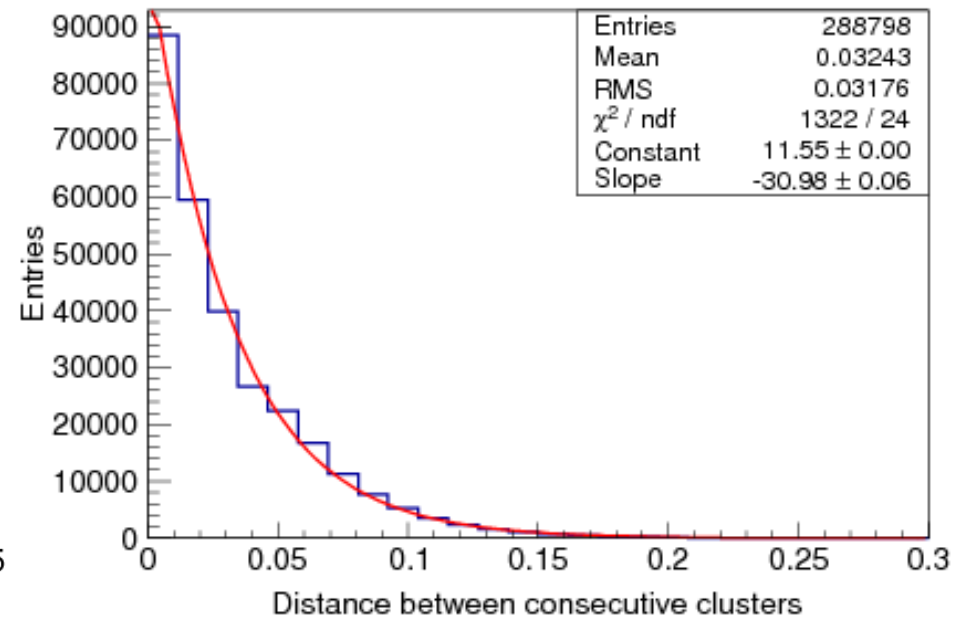
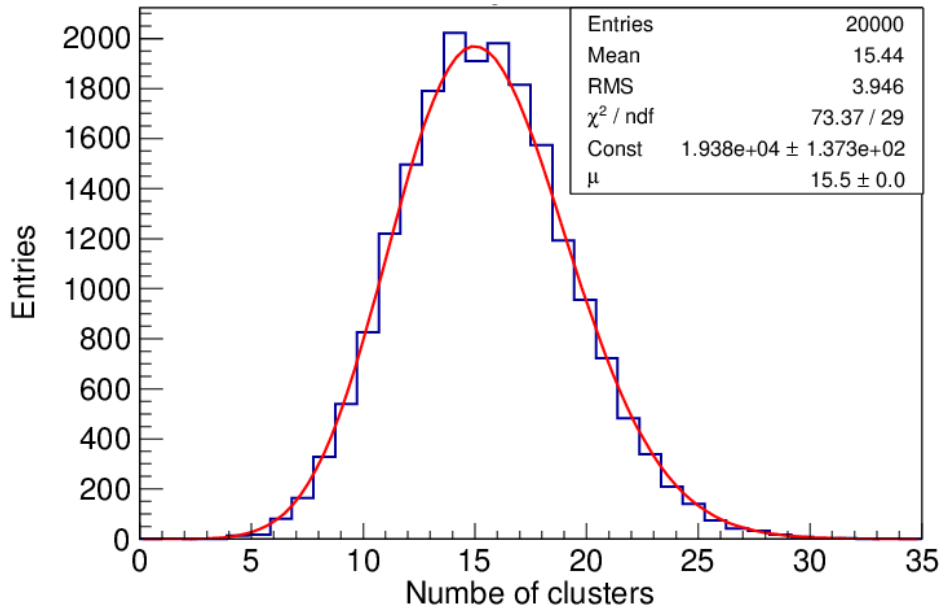
Number of Electrons in a Cluster in drift area (~5mm).

For range 20~100, the sampled value from the Landau fit.

Range 20~100

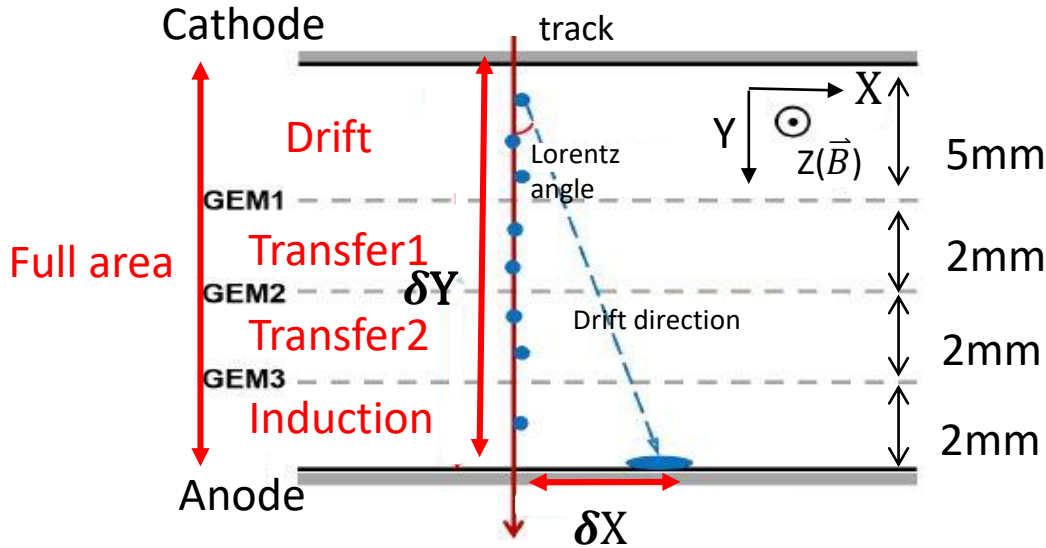


Primary ionization

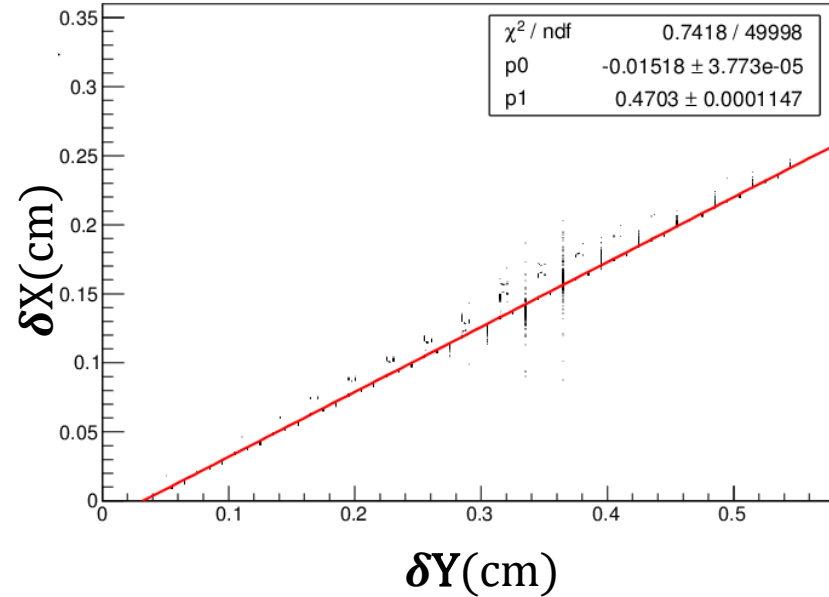


In drift area ($\sim 5\text{mm}$), the produced electron clusters is a Poisson distribution. An Exponential probability gives the distance between two consecutive clusters.

Lorentz Angle



δX vs δY (Drift)

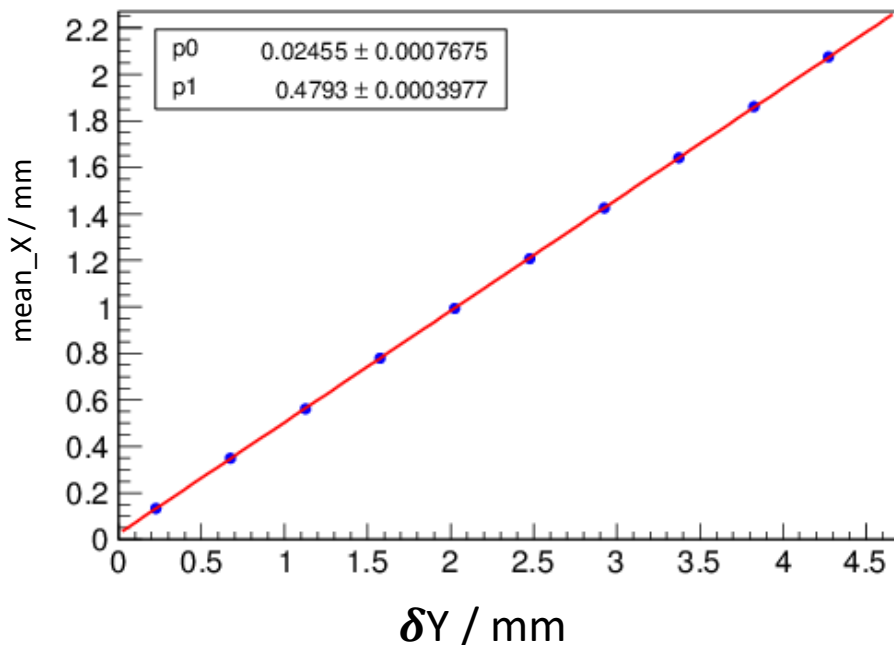


- In each area, simulate 1000 electrons separately in 50 equidistant bins.
- X is the direction which is perpendicular to E and B
- Y is the direction of electric field
- The Lorentz angle can be extracted from the plot

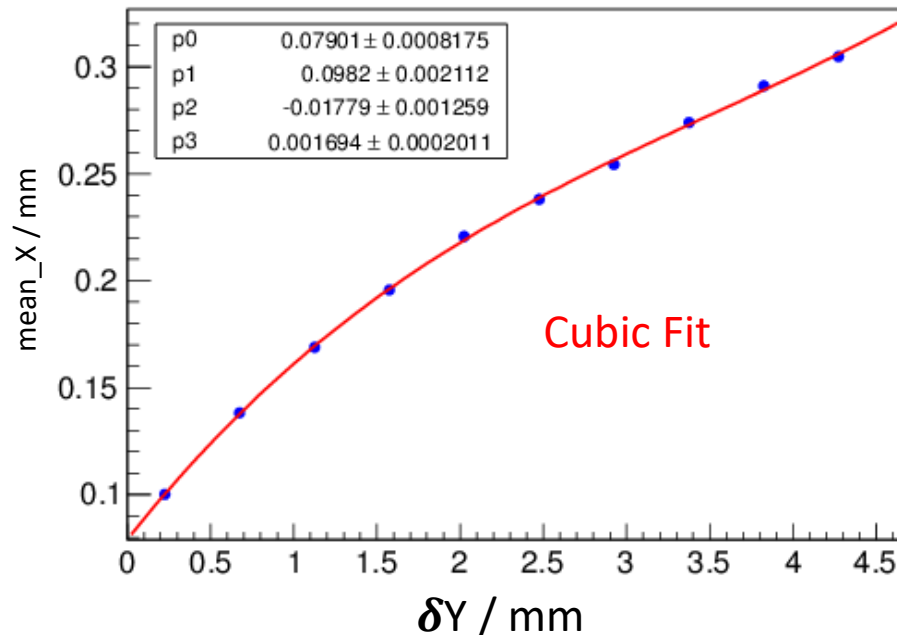
	Drift	Transfer1	Transfer2	Induction	Full area
Lorentz Angle	25.2	10.5	10.5	6.0	16.1
Electric Field (kV/cm)	1.5	3	3	5	

Electron shift(Gem1)

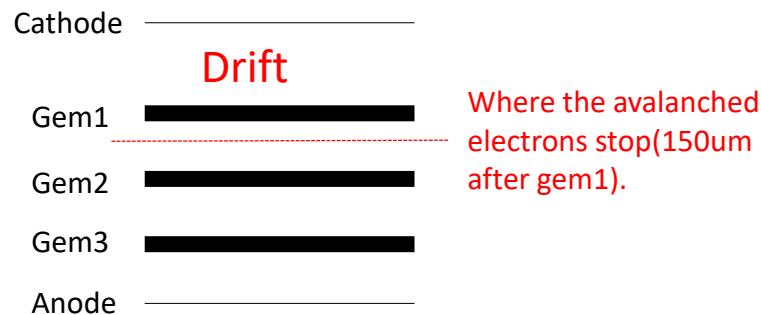
Mean_X vs δY



Sigma_X vs δY

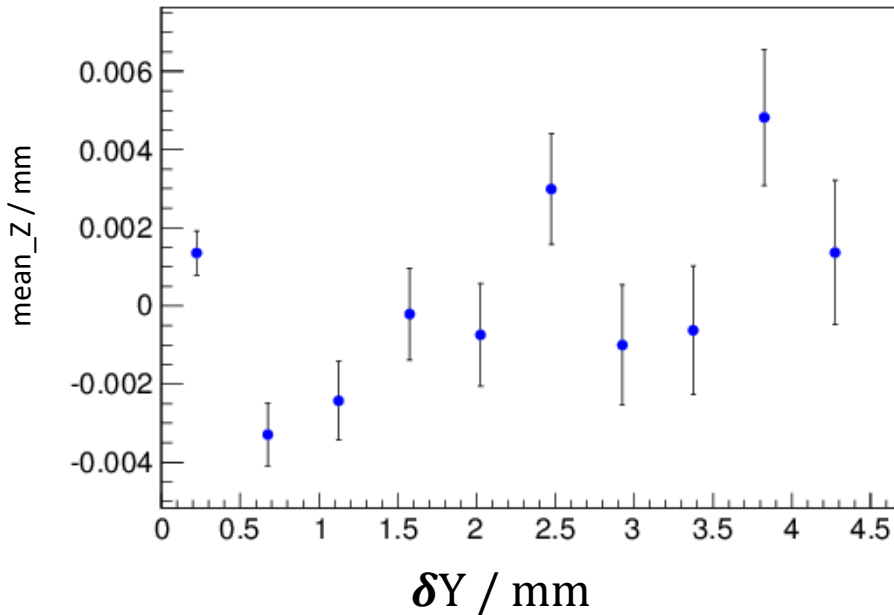


- In drift area, simulate 20k electrons separately in 10 equidistant bins.
- Generate a electron with uniform distribution in X&Z direction $[-0.14, 0.14]$ mm, Y direction[bin width].
- Get the mean & sigma of avalanched electrons' shift in X direction vs δr .

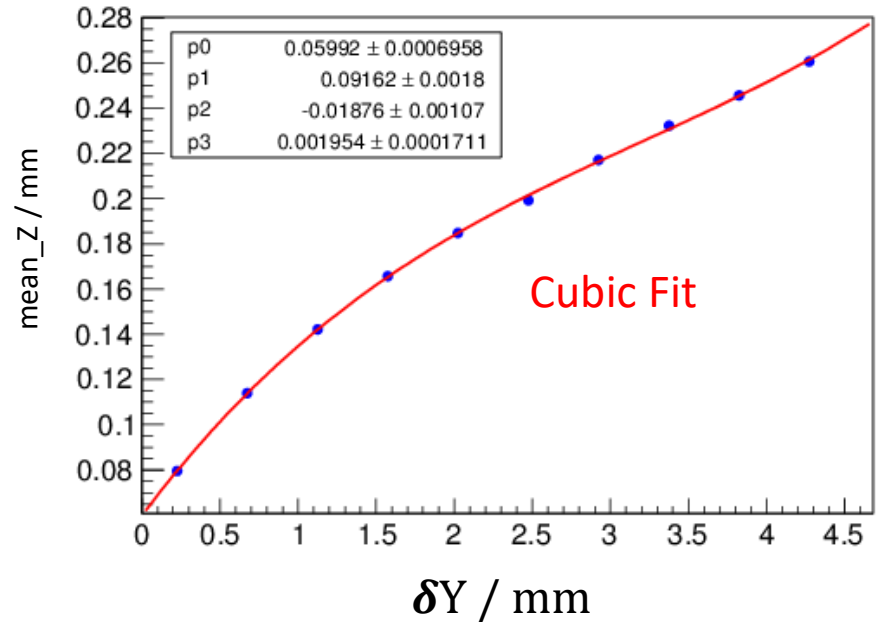


Electron shift(Gem1)

Mean_Z vs δr



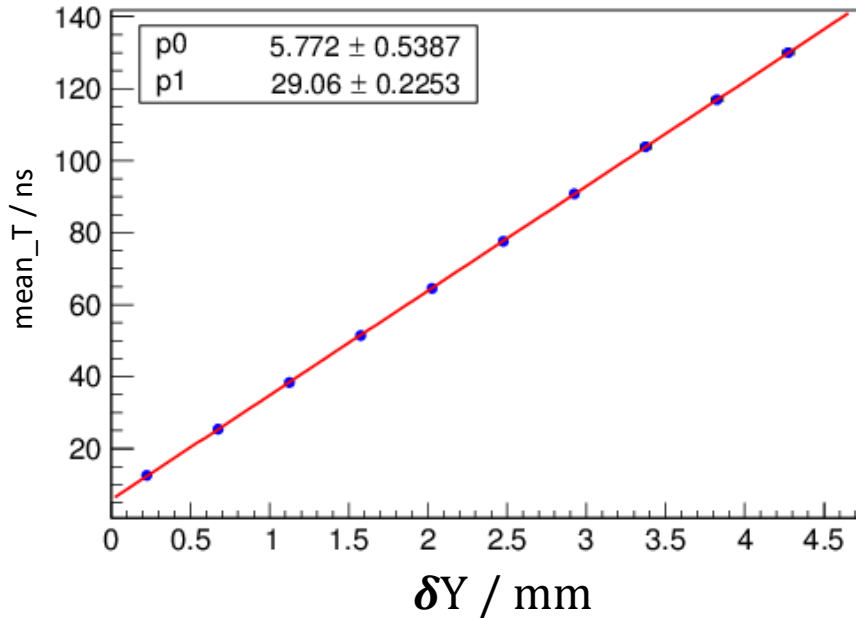
Sigma_Z vs δr



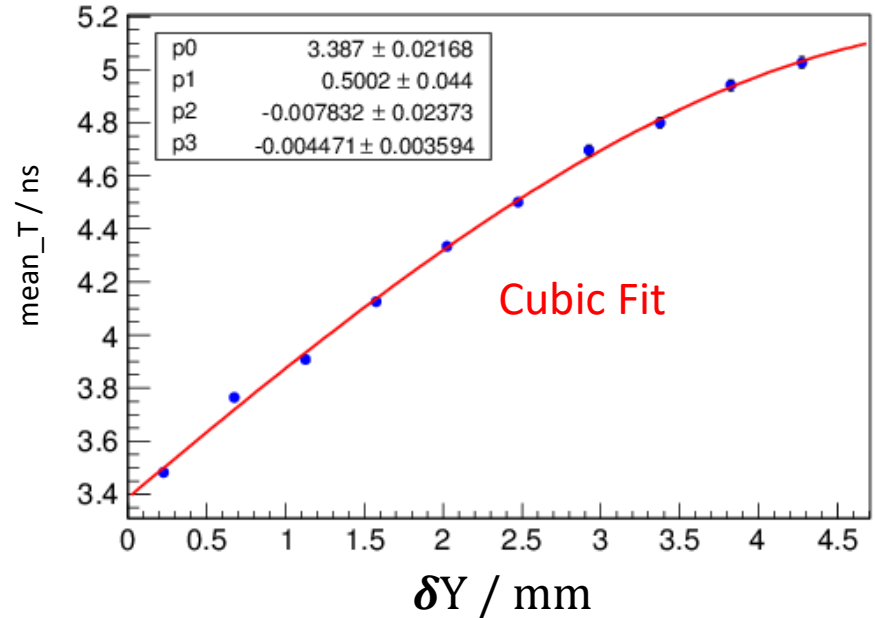
- In drift area, simulate 20k electrons separately in 10 equidistant bins.
- Generate a electron with uniform distribution in X&Z direction[-0.14, 0.14]mm, Y direction[bin width].
- Get the mean & sigma of avalanched electrons' shift in Z direction vs δr .

Electron shift(Gem1)

Mean_T vs δr



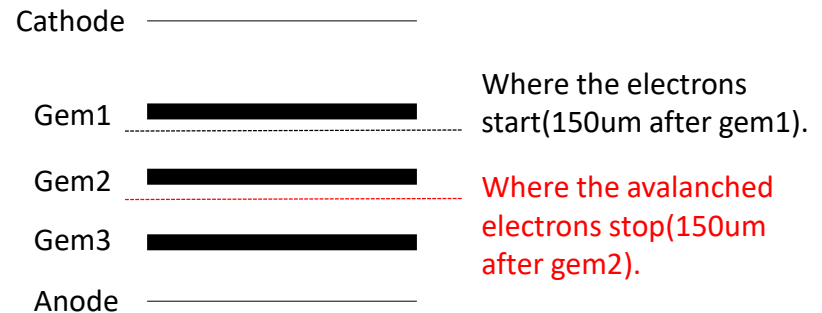
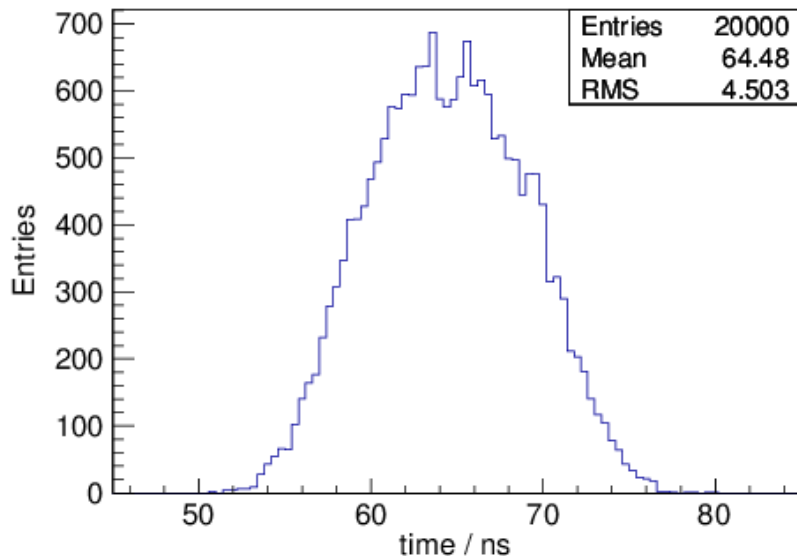
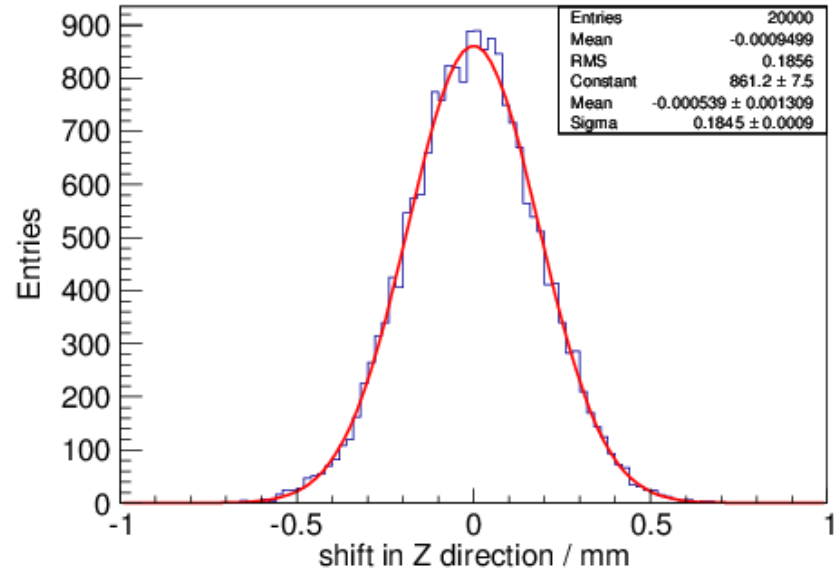
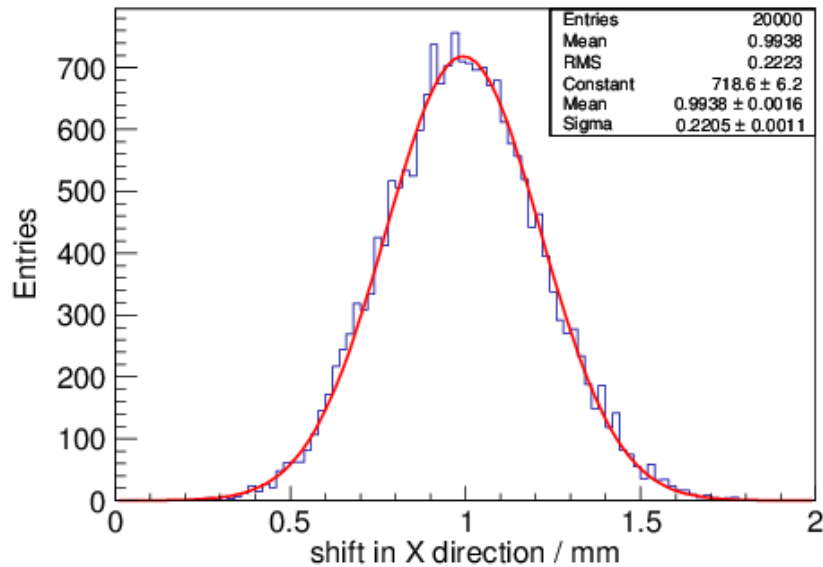
Sigma_T vs δr



- In drift area, simulate 20k electrons separately in 10 equidistant bins.
- Generate a electron with uniform distribution in X&Z direction $[-0.14, 0.14]$ mm, Y direction[bin width].
- Get the mean & sigma of avalanched electrons' drift time vs δr .

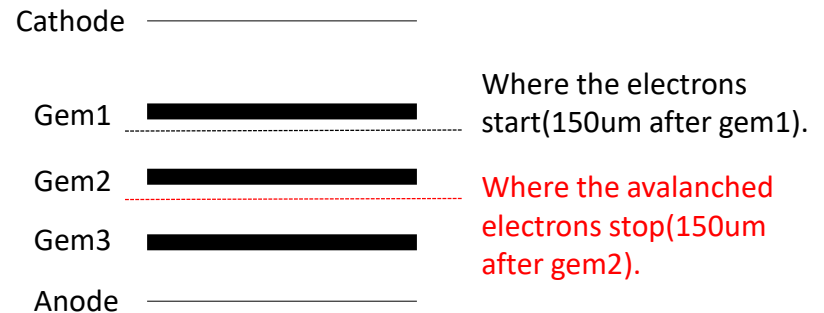
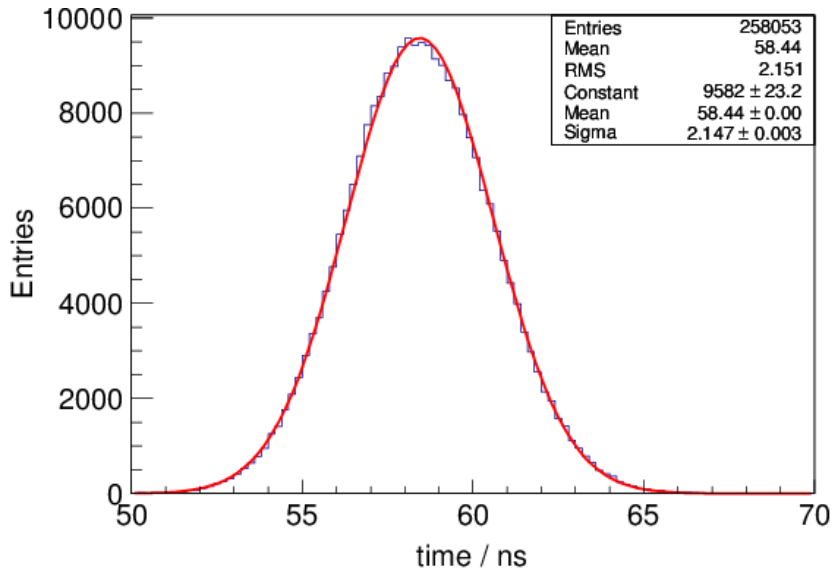
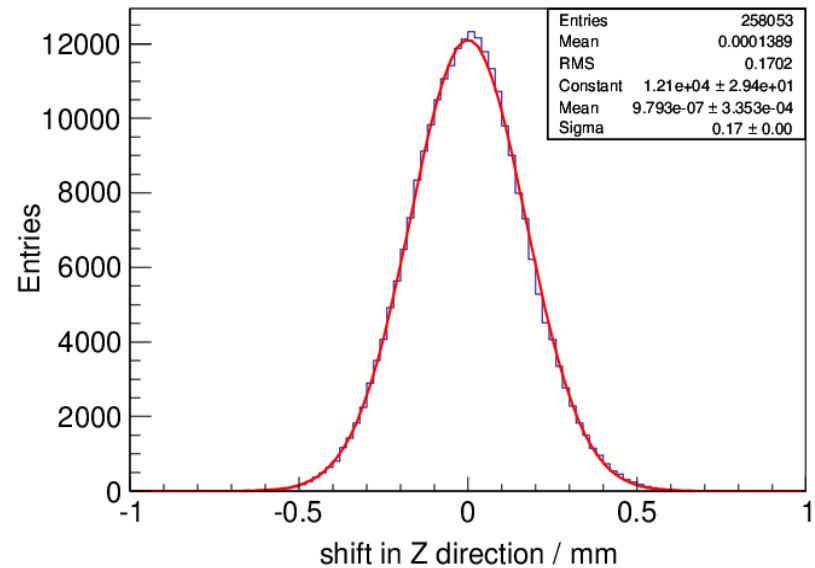
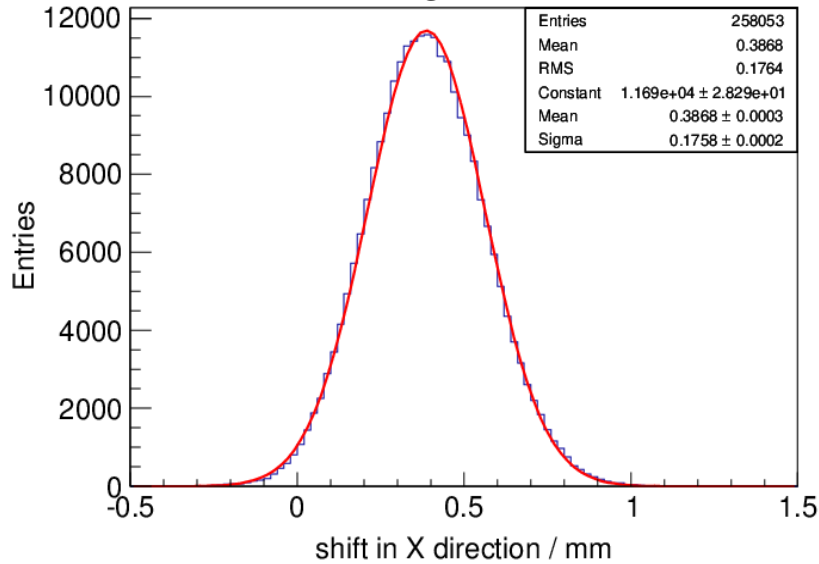
Electron shift(Gem1)

Simulate 20k electrons [2.75, 3.20]mm (uniform distribution) before gem₁, then get the shift of avalanched electrons in X & Z direction 150um after gem₁.



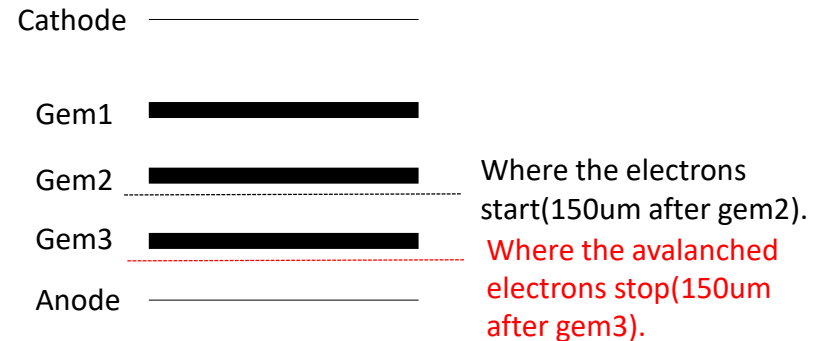
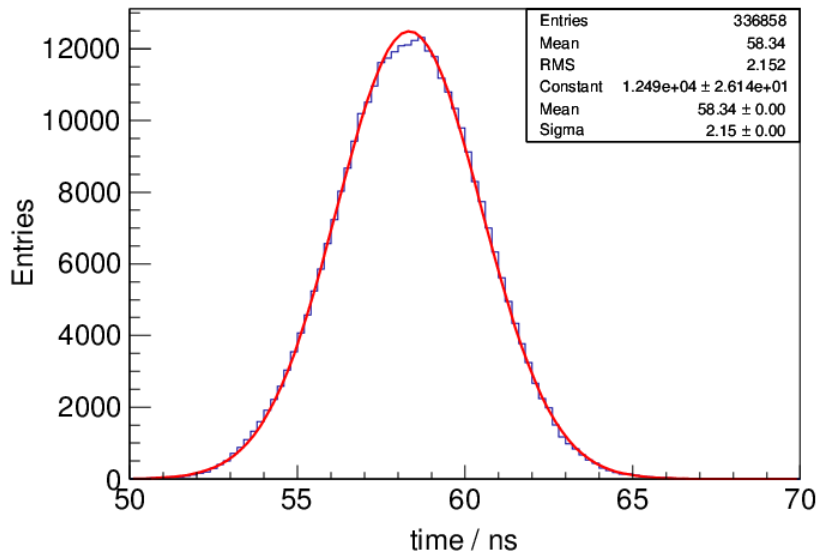
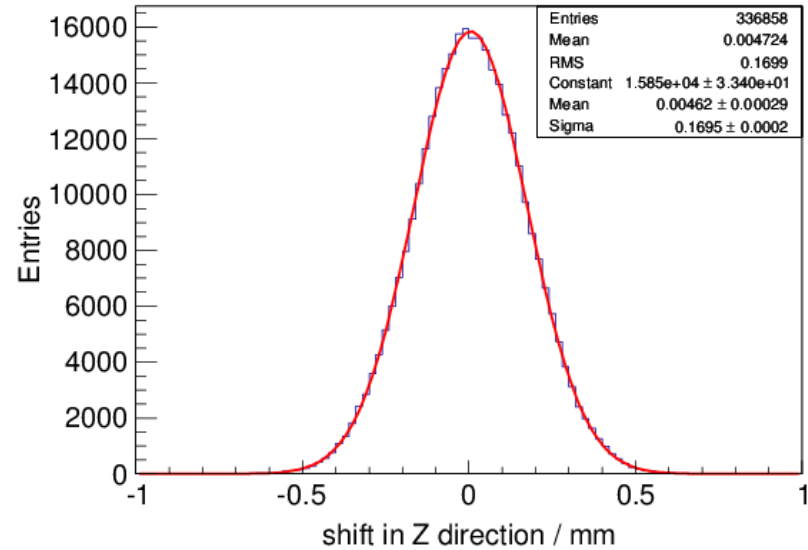
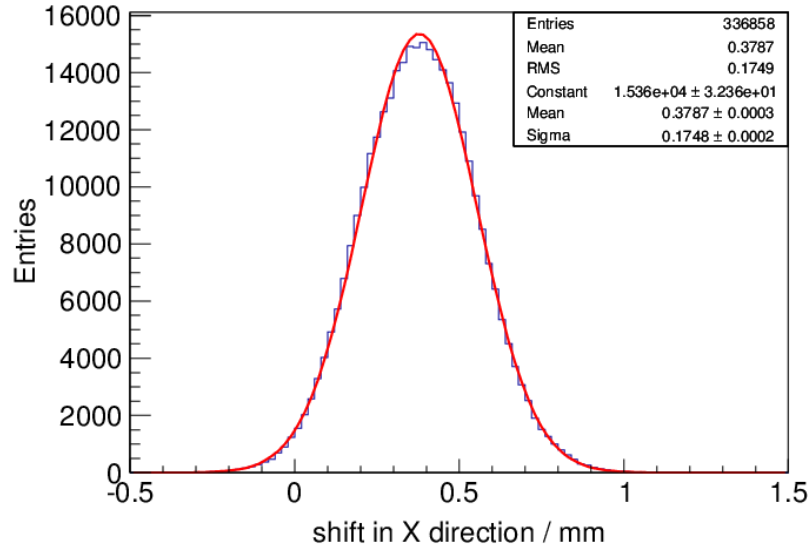
Electron shift(Gem2)

Simulate 20k electrons 150um after gem₁, then get the shift of avalanched electrons in X & Z direction 150um after gem₂.



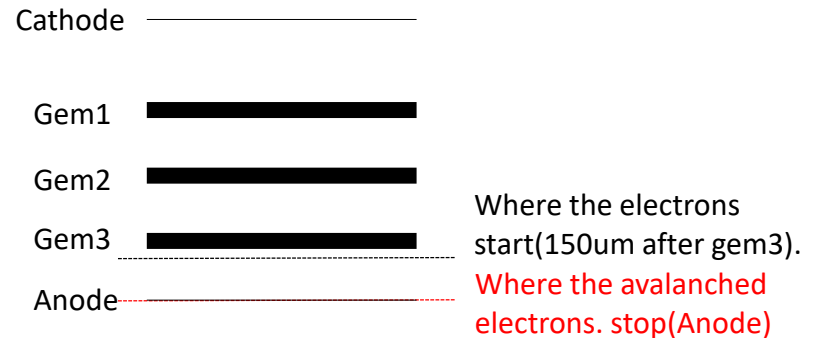
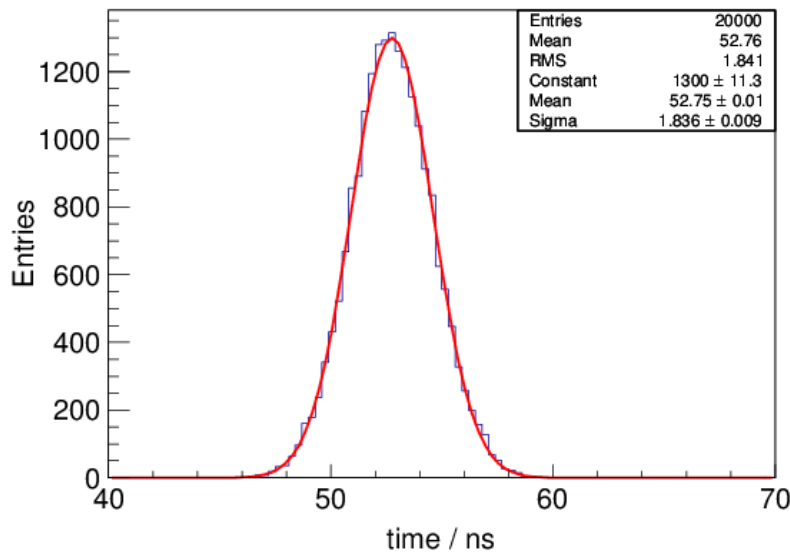
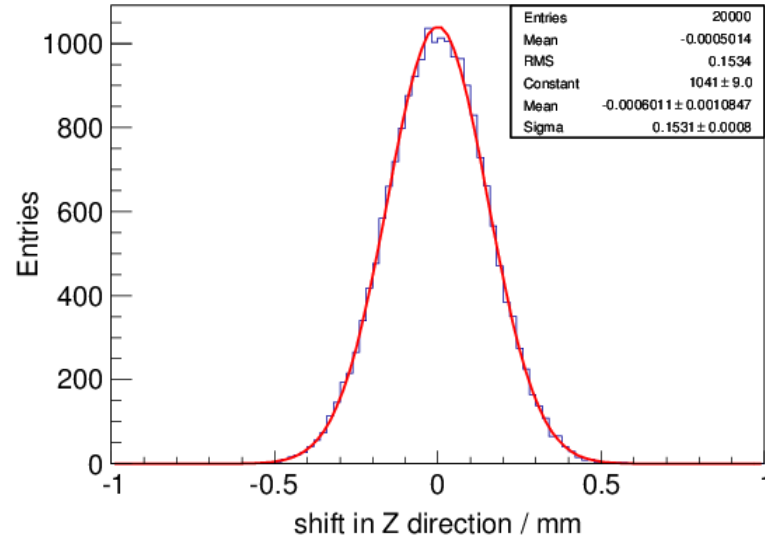
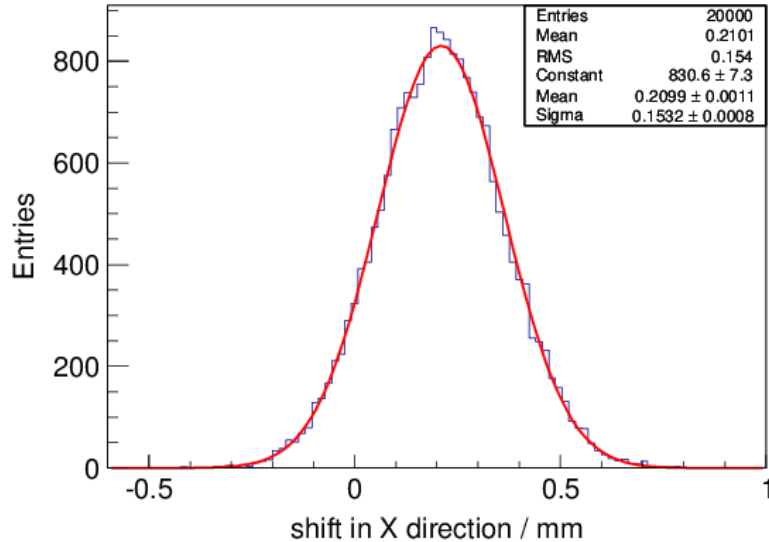
Electron shift(Gem3)

Simulate 20k electrons 150um after gem2, then get the shift of avalanched electrons in X & Z direction 150um after gem3.

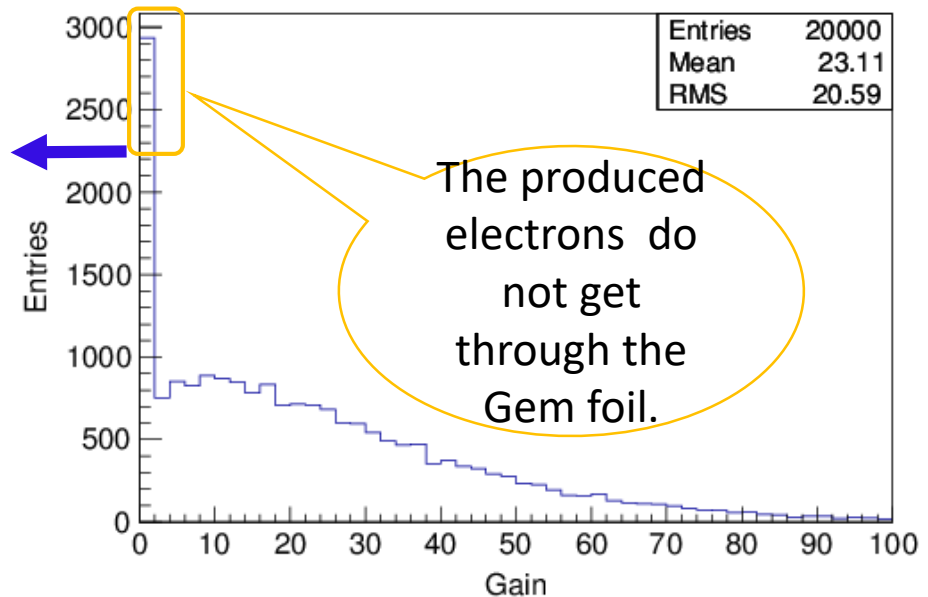
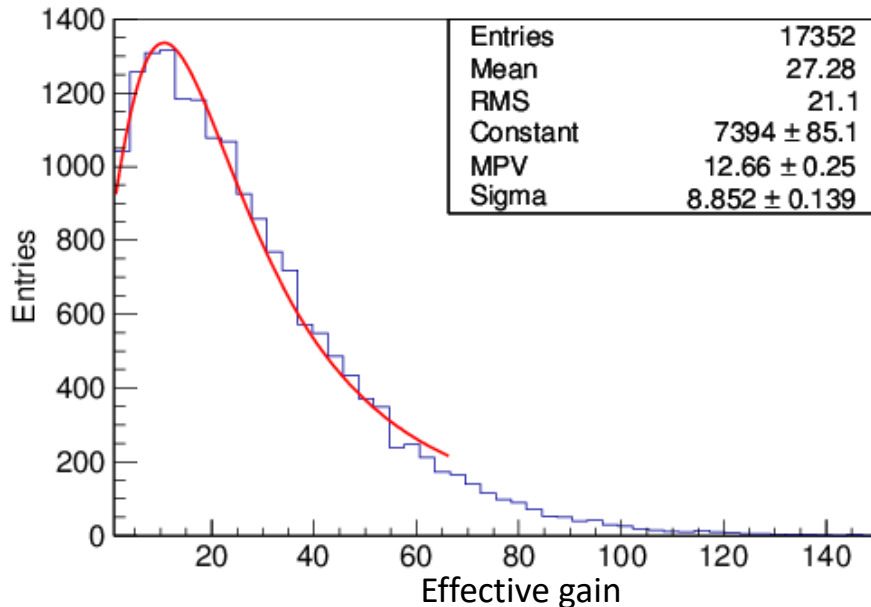


Electron shift(Induction)

Simulate 20k electrons 150um after gem3, then get the shift of avalanched electrons in X & Z direction in Anode.

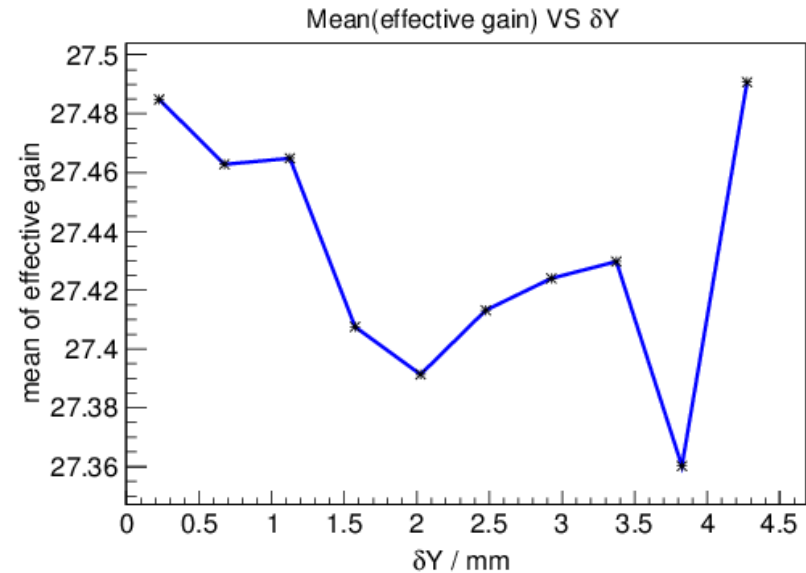
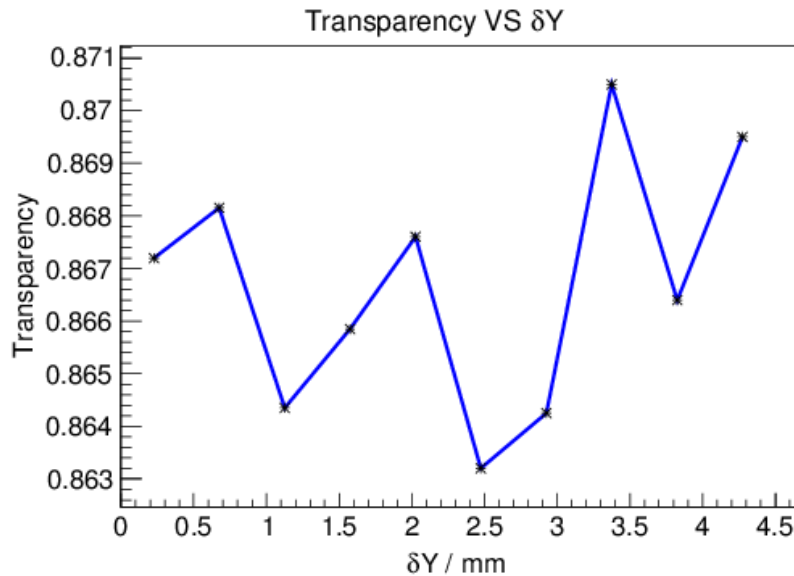


Avalanche & Gain ----Gem1



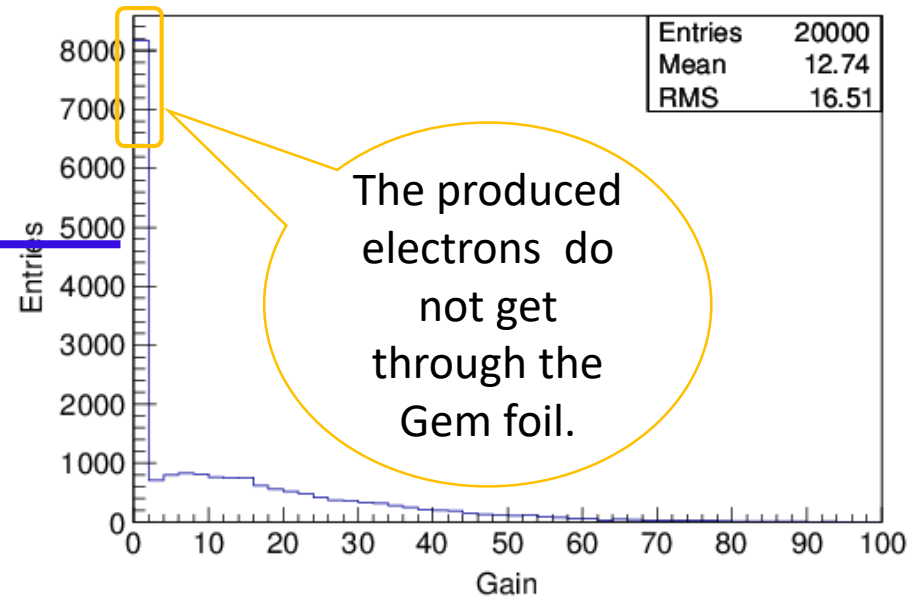
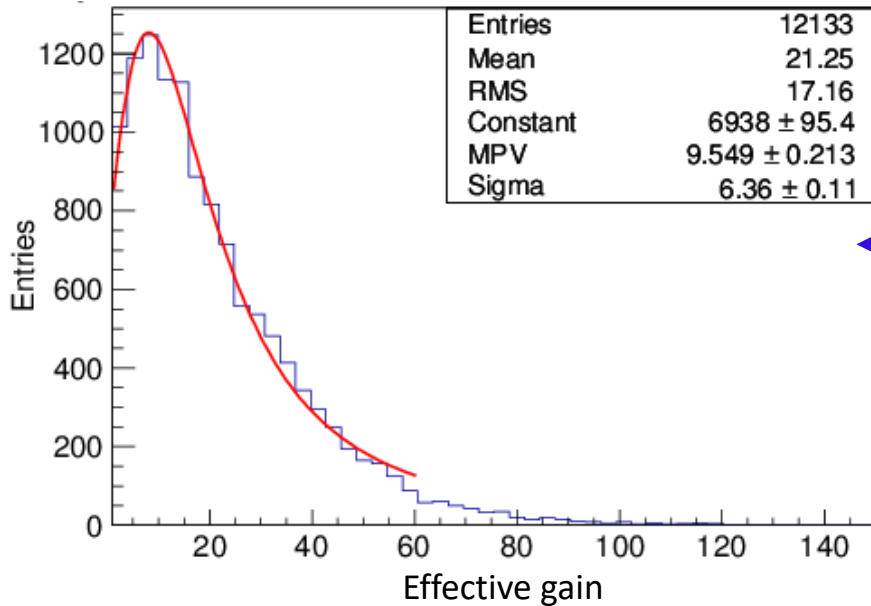
- Set an electron [2.75, 3.20]mm (uniform distribution) before the Gem1 foil and count multiplied electrons 150 μ m after the Gem1 foil.
- Effective gain: Electrons get through the Gem1 foil, about 86.76%. It is sampled from a Landau.

Avalanche & Gain ----Gem1



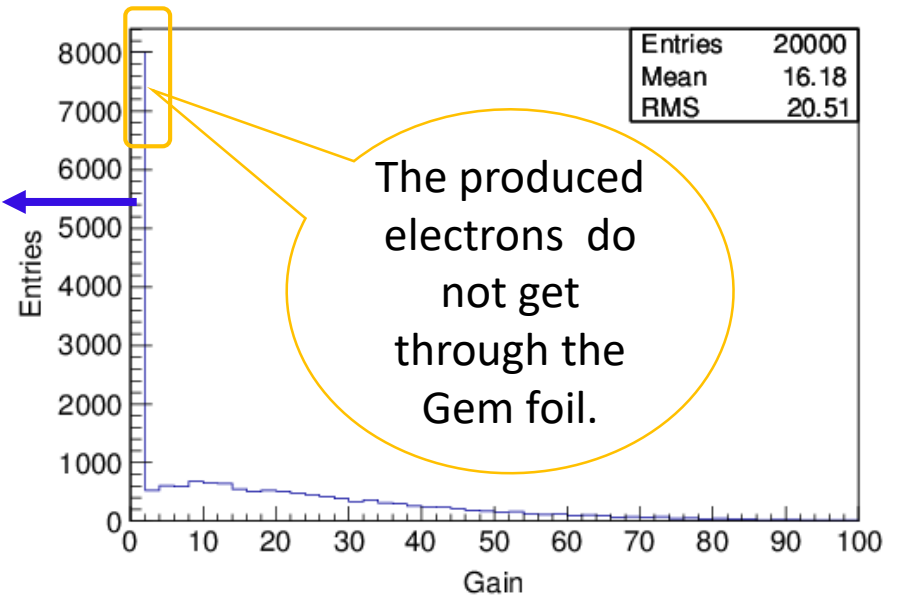
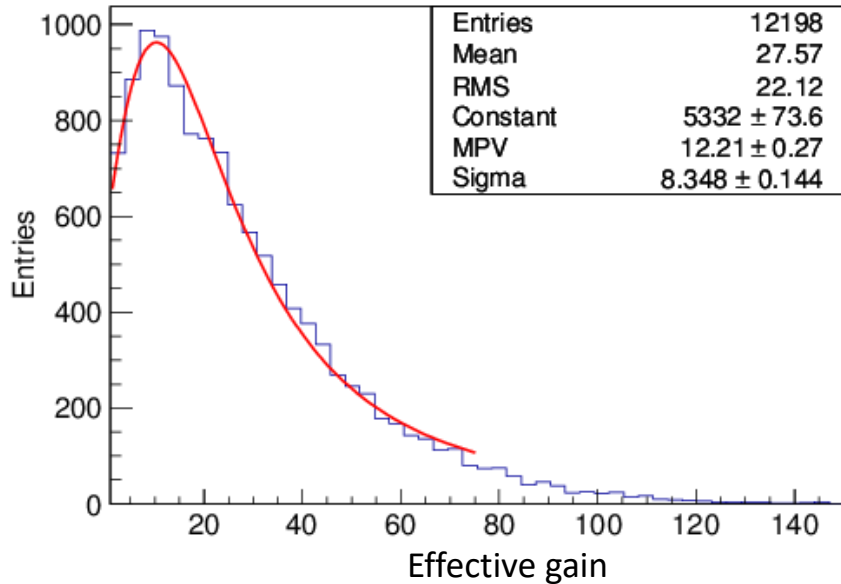
- In drift area, simulate **20k** electrons separately in **10** equidistant bins.
- Get the mean of effective gain and transparency vs δY .

Avalanche & Gain ----Gem2



- Set an electron 150 μm after the Gem1 foil and count multiplied electrons 150 μm after the Gem2 foil.
- Effective gain: Electrons get through the Gem2 foil, about 60.67%. It is sampled from a Landau.

Avalanche & Gain ----Gem3



- Set an electron 150 μm after the Gem2 foil and count multiplied electrons 150 μm after the Gem3 foil.
- Effective gain: Electrons get through the Gem3 foil, about 60.99%. It is sampled from a Landau.